## NSN 5961-01-079-5756

A110a0

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| Overall Length:  |
|--|
| Between 0.166 inches and 0.180 inches  |
| Overall Diameter:  |
| Between 0.078 inches and 0.084 inches  |
| Semiconductor Material:  |
| Silicon  |
| Voltage Rating In Volts Per Characteristic:  |
| 30.0 collector to emitter voltage, $$ dc and $5.0$ emitter to collector voltage, $$ dc |
| Power Rating Per Characteristic:   |
| 75.0 milliwatts small-signal input power, common-collector absolute                    |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
| <del></del>  |
| Demilitarization:  |
| No   |
| Fiig:  |